#### **NPN Silicon Epitaxial Planar Transistor**

for switching and amplifier applications. Especially suitable for AF-driver stages and low power output stages.



1.Base 2.Collector 3.Emitter SOT-89 Plastic Package

## Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$V_{CBO}$	40	V
Collector Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter Base Voltage	$V_{EBO}$	6	V
Collector Current	I <sub>C</sub>	1.5	А
Power Dissipation	P <sub>tot</sub>	625	mW
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature Range	T <sub>Stg</sub>	- 55 to + 150	°C

### Characteristics at T<sub>a</sub> = 25℃

Parameter	Symbol	Min.	Тур.	Max.	Unit
DC Current Gain at $V_{CE} = 1 \text{ V}$ , $I_C = 5 \text{ mA}$	h <sub>FF</sub>	45	_	_	_
at $V_{CE} = 1 \text{ V}$ , $I_C = 0 \text{ m/V}$ at $V_{CE} = 1 \text{ V}$ , $I_C = 100 \text{ mA}$ Current Gain Group C	h <sub>FF</sub>	120	-	200	-
D	h <sub>FE</sub>	160	-	300	-
at $V_{CE} = 1 \text{ V}, I_{C} = 800 \text{ mA}$	h <sub>FE</sub>	40	-	-	-
Collector Base Cutoff Current at V <sub>CB</sub> = 35 V	I <sub>CBO</sub>	-	-	100	nA
Emitter Base Cutoff Current at V <sub>EB</sub> = 6 V	I <sub>EBO</sub>	-	-	100	nA
Collector Base Breakdown Voltage at $I_C = 100 \mu A$	V <sub>(BR)CBO</sub>	40	ı	-	V
Collector Emitter Breakdown Voltage at I <sub>C</sub> = 2 mA	V <sub>(BR)CEO</sub>	25	ı	-	V
Emitter Base Breakdown Voltage at $I_E = 100 \mu A$	$V_{(BR)EBO}$	6	-	-	V
Collector Emitter Saturation Voltage at $I_C = 800 \text{ mA}$ , $I_B = 80 \text{ mA}$	V <sub>CE(sat)</sub>	-	-	0.5	V
Base Emitter Saturation Voltage at $I_C = 800 \text{ mA}$ , $I_B = 80 \text{ mA}$	$V_{BE(sat)}$	-	-	1.2	V
Base Emitter Voltage at $I_C = 10$ mA, $V_{CE} = 1$ V	$V_{BE}$	-	-	1	V
Gain Bandwidth Product at $V_{CE} = 10 \text{ V}$ , $I_C = 50 \text{ mA}$	f <sub>T</sub>	100	-	-	MHz
Collector Base Capacitance at $V_{CB} = 10 \text{ V}$ , $f = 1 \text{ MHz}$	СОВ	-	9	-	pF

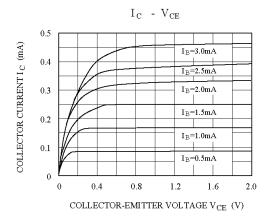


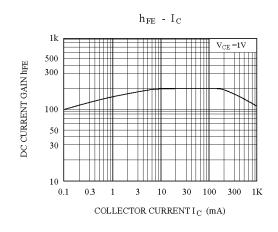


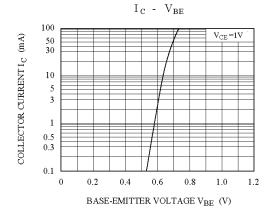


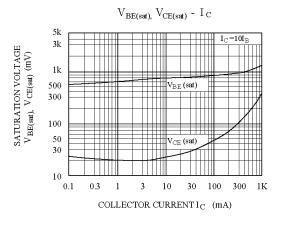


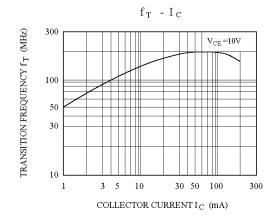


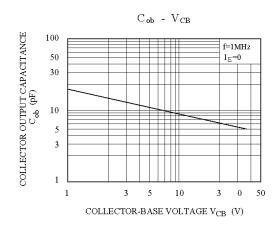














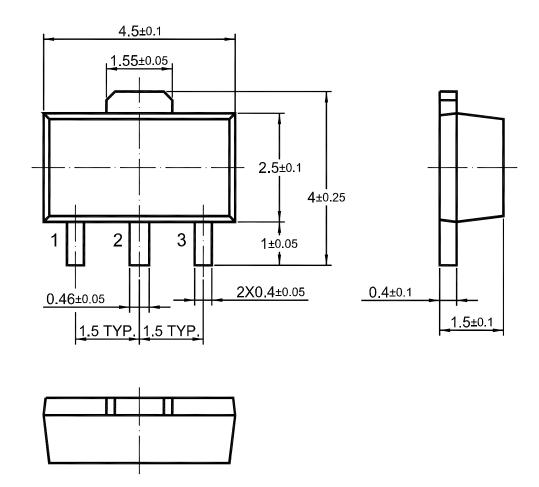








#### **SOT-89 PACKAGE OUTLINE**



Dimensions in mm











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